



### Features

- Half-bridge SCR configuration integrated
- In a single package
- High-thermalconductivity DBC insulation for excellent heat dissipation
- Vacuum soldering technology for enhanced reliability

### Product Summary

### Applications

- Heating control
- Light control system
- DC motor

### Absolute Maximum Ratings (@ T<sub>C</sub> = 25°C unless otherwise specified)

Non-repetitive	P	-repetitive	689 f	213.72	224.64	0.48	27.84	re f	348.36	224.64	0.48	27.84	re f	390.84	224.64	0.48



Electrical Characteristics (@  $T_C = 25^\circ\text{C}$  unless otherwise specified)

Parameter	Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Peak forward voltage	$I_T=210\text{A}$ , $t_P=380\text{ V}$	$V_T$			1.80	V
Repetitive peak offstate current	$V_D = V_{DRM}, T_{vj} = 25$	$I_{DRM}$			100	A
	$V_D = V_{DRM}, T_{vj} = 125$				30	mA
Reverse leakage current	$V_R = V_{RRM}, T_{vj} = 25$	$I_{RRM}$			100	A
	$V_R = V_{RRM}, T_{vj} = 125$				30	mA
Threshold voltage	For power loss calculation only $T_{vj} = 125$	$V_{TO}$			0.92	V
Dynamic resistance	$T_{vj} = 125$	$r_T$			3.3	P
Triggering gate current	$V_D=12\text{V}$ $R_L$	$I_{GT}$	20		120	mA
Holding current	$I_T=1\text{A}$	$I_H$			250	mA
Latching current	$I_G=1.2 I_T$	$I_L$			300	mA
Critical rate of rise of voltage	$V_D=2/3 V_{RRM}$ $T_{vj}=125$ - Gate Open	$dv/dt$	1000			9 V
Triggering gate voltage	$V_D=12\text{V}$ $R_L$	$V_{GT}$			1.8	V
Non triggering gate voltage	$V_D=0.5 V_{DRM}$ $T_{vj}=125$	$V_{GD}$	0.25			V

Thermal Characteristics (@  $T_C = 25^\circ\text{C}$  unless otherwise specified)

Parameter	Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance, junction to case						

Thermal resistance,  
junction to case





Circuit Diagram

